



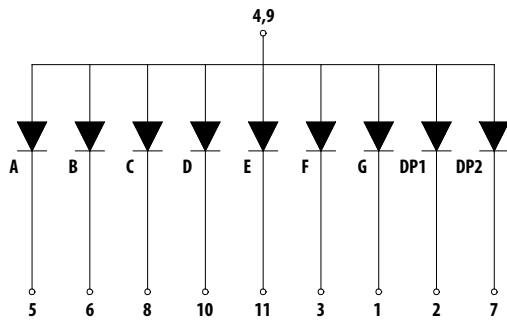
### Pin Connection (Common Anode)

PIN No	Connection
1	CATHODE G
2	CATHODE DP1
3	CATHODE F
4	COMMON ANODE
5	CATHODE A
6	CATHODE B
7	CATHODE DP2
8	CATHODE C
9	COMMON ANODE
10	CATHODE D
11	CATHODE E

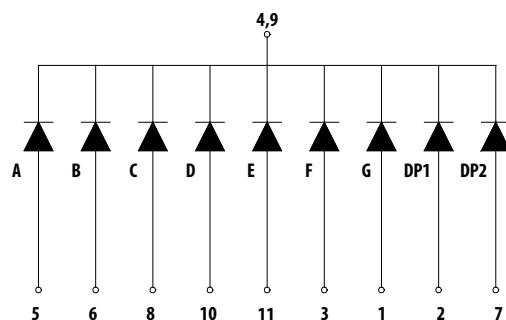
### Pin Connection (Common Cathode)

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1	ANODE G
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5	ANODE A
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7	ANODE DP2
8	ANODE C
9	COMMON CATHODE
10	ANODE D
11	ANODE E

### Internal Circuit Diagram (Common Anode)



### Internal Circuit Diagram (Common Cathode)



### Absolute Maximum Ratings @ $T_A=25^\circ$

Parameter	Green/Yellow/Red/Orange	Unit
Power Dissipation Per Segment	65	mW
Peak Forward Current Per Segment (1/10 Duty Cycle, .0.1ms pulse width)	100	mA
Continuous Forward Current Per Segment Derating Linearly From 25°C Per Segment	25 0.25	mA mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-40°C to +105°C	
Storage Temperature Range	-40°C to +105°C	

## Electrical / Optical Characteristics @ T<sub>A</sub>=25°C

### Green

Parameters	Symbol	Min	Typ	Max	Unit	Test Condition
Average Luminous Intensity	I <sub>V</sub>	3.4	6	-	mcd	I <sub>F</sub> = 10mA
Emissions Wavelength	η <sub>p</sub> /λ <sub>d</sub>	-	572/571	-	nm	I <sub>F</sub> = 20mA
Spectral Line Half-Width	Δλ	-	20	-	nm	I <sub>F</sub> = 20mA
Forward Voltage, Per Segment	V <sub>F</sub>	-	2.1	2.6	V	I <sub>F</sub> = 20mA
Reverse Current, Per Segment	I <sub>R</sub>	-	-	100	μA	V <sub>R</sub> = 5V
Luminous Intensity Matching Ratio	I <sub>V-M</sub>	-	-	2:1	-	I <sub>F</sub> = 10mA

### Yellow

Parameters	Symbol	Min	Typ	Max	Unit	Test Condition
Average Luminous Intensity	I <sub>V</sub>	3.4	8.0	-	mcd	I <sub>F</sub> = 10mA
Emissions Wavelength	λ <sub>p</sub> /λ <sub>d</sub>	-	591/589	-	nm	I <sub>F</sub> = 20mA
Spectral Line Half-Width	Δλ	-	15	-	nm	I <sub>F</sub> = 20mA
Forward Voltage, Per Segment	V <sub>F</sub>	-	2.1	2.6	V	I <sub>F</sub> = 20mA
Reverse Current, Per Segment	I <sub>R</sub>	-	-	100	μA	V <sub>R</sub> = 5V
Luminous Intensity Matching Ratio	I <sub>V-M</sub>	-	-	2:1	-	I <sub>F</sub> = 10mA

### Red

Parameters	Symbol	Min	Typ	Max	Unit	Test Condition
Average Luminous Intensity	I <sub>V</sub>	3.4	7.5	-	mcd	I <sub>F</sub> = 10mA
Emissions Wavelength	λ <sub>p</sub> /λ <sub>d</sub>	-	632/624	-	nm	I <sub>F</sub> = 20mA
Spectral Line Half-Width	Δλ	-	20	-	nm	I <sub>F</sub> = 20mA
Forward Voltage, Per Segment	V <sub>F</sub>	-	2.0	2.6	V	I <sub>F</sub> = 20mA
Reverse Current, Per Segment	I <sub>R</sub>	-	-	100	μA	V <sub>R</sub> = 5V
Luminous Intensity Matching Ratio	I <sub>V-M</sub>	-	-	2:1	-	I <sub>F</sub> = 10mA

### Orange

Parameters	Symbol	Min	Typ	Max	Unit	Test Condition
Average Luminous Intensity	I <sub>V</sub>	3.4	8.5	-	mcd	I <sub>F</sub> = 10mA
Emissions Wavelength	λ <sub>p</sub> /λ <sub>d</sub>	-	611/605	-	nm	I <sub>F</sub> = 20mA
Spectral Line Half-Width	Δλ	-	20	-	nm	I <sub>F</sub> = 20mA
Forward Voltage, Per Segment	V <sub>F</sub>	-	2.1	2.6	V	I <sub>F</sub> = 20mA
Reverse Current, Per Segment	I <sub>R</sub>	-	-	100	μA	V <sub>R</sub> = 5V
Luminous Intensity Matching Ratio	I <sub>V-M</sub>	-	-	2:1	-	I <sub>F</sub> = 10mA

Typical Electrical / Optical characteristic curves @  $T_A=25^\circ\text{C}$

Green



Figure 1. Relative Luminous Intensity vs. Wavelength



Figure 2. Relative Luminous Intensity vs. Forward Current

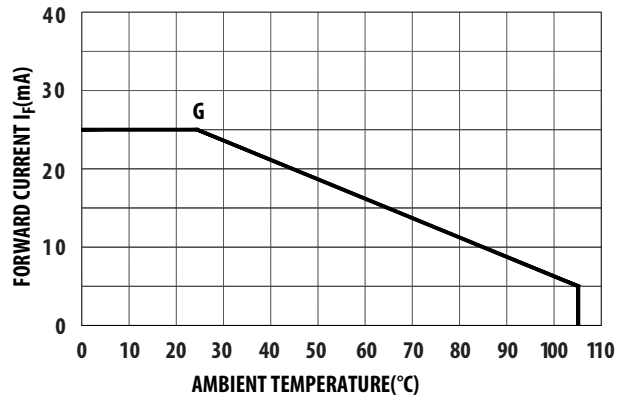


Figure 3. Allowable DC Current vs. Ambient Temperature



Figure 4. Forward Current vs. Forward Voltage

Yellow

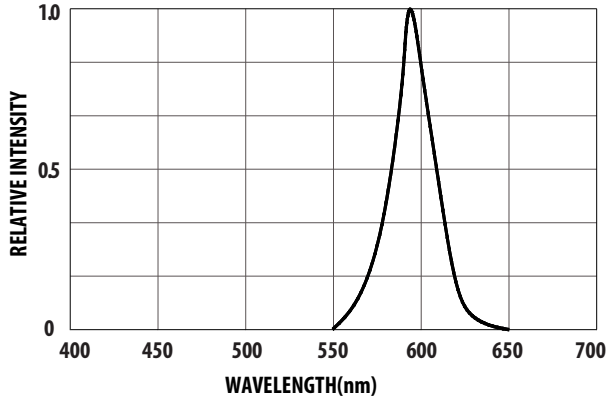


Figure 1. Relative Intensity vs. Wavelength

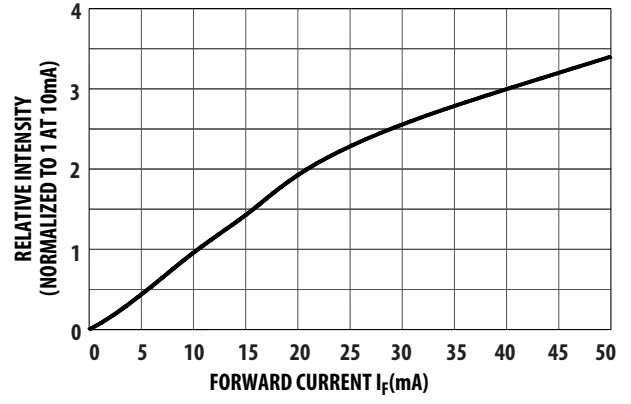


Figure 2. Relative Intensity vs. Forward Current

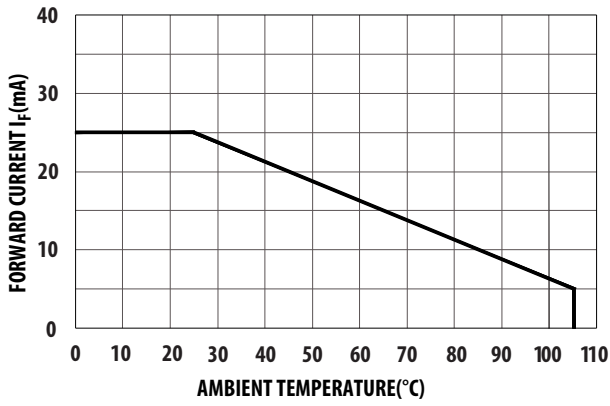


Figure 3. Allowable DC Current vs. Ambient Temperature

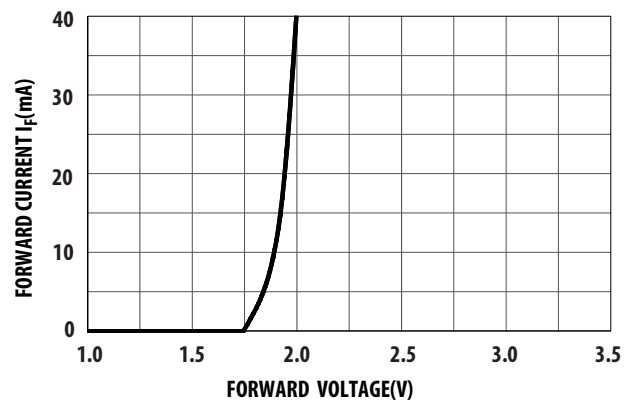


Figure 4. Forward Current vs. Forward Voltage

Red

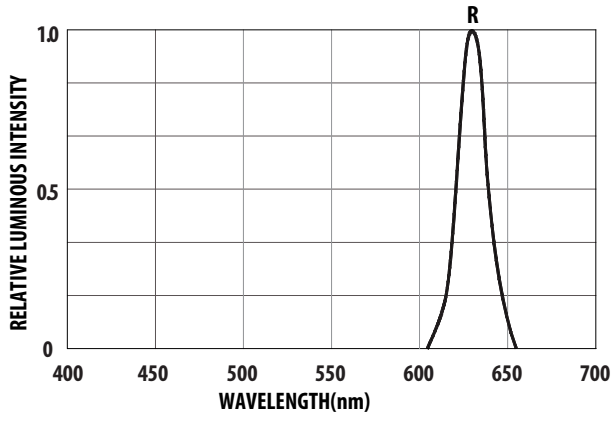


Figure 1. Relative Luminous Intensity vs. Wavelength

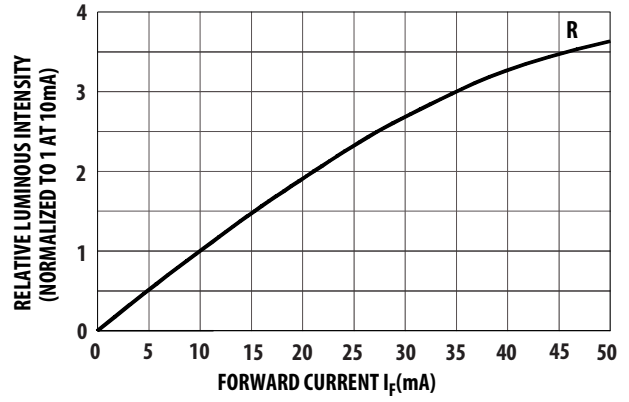


Figure 2. Relative Luminous Intensity vs. Forward Current

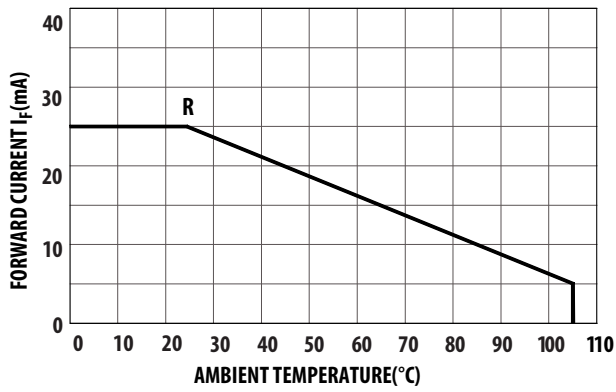


Figure 3. Allowable DC Current vs. Ambient Temperature

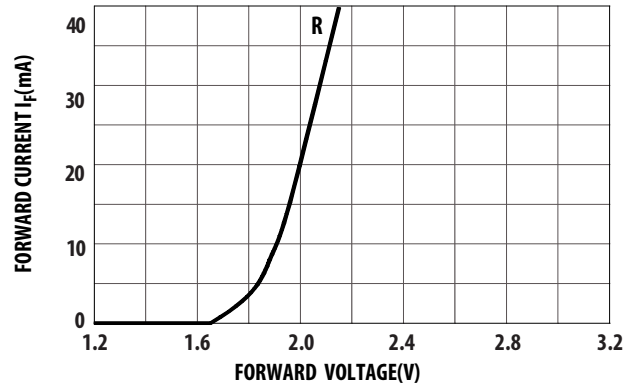


Figure 4. Forward Current vs. Forward Voltage

### Orange



Figure 1. Relative Intensity vs. Wavelength



Figure 2. Relative Intensity vs. Forward Current

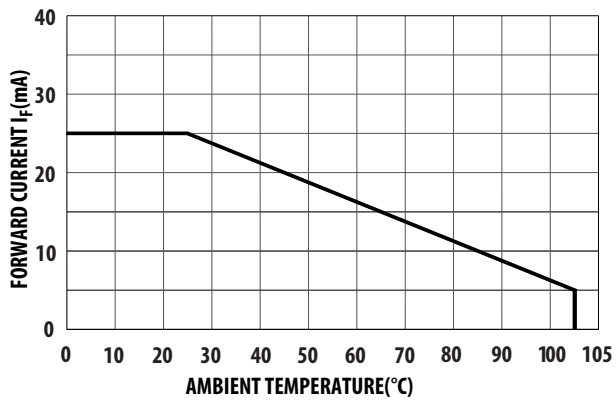


Figure 3. Allowable DC Current vs. Ambient Temperature



Figure 4. Forward Current vs. Forward Voltage

## Intensity Bin Limits (mcd)

### Yellow / Red / Orange / Green

IV Bin Category	Min.	Max
L	3.401	5.400
M	5.401	8.600
N	8.601	13.700
P	13.701	21.800

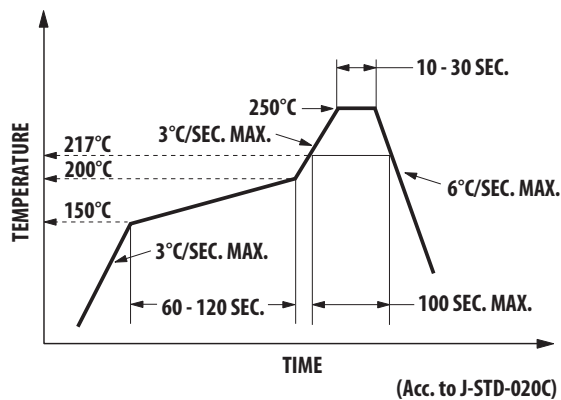
Tolerance:  $\pm 15\%$

Notes:

- Bin categories are established for classification of products. Products may not be available in all categories. Please contact your Avago representative for information on currently available bins.

## SMT Soldering Profile

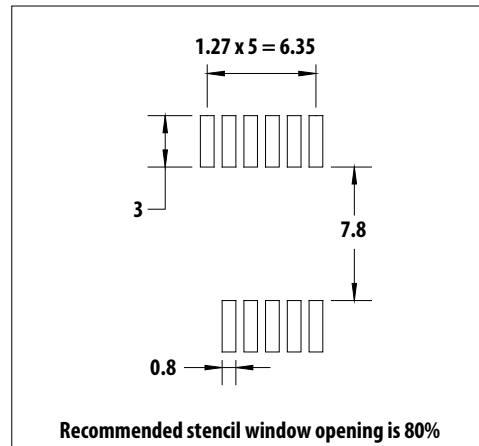
### Pb free reflow soldering Profile



Notes:

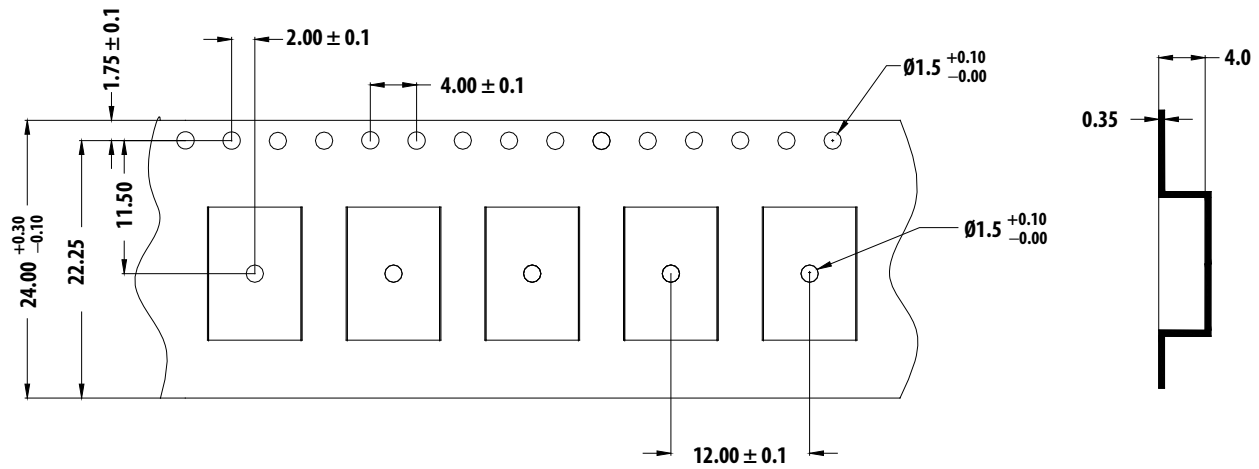
- The peak temperature refers to the peak package body temperature.
- Number of reflow process shall be limited to maximum 2 times only. Cooling process to normal temperature is required between first and second soldering process.

## Recommended soldering pattern (unit: mm)





**Tape specification (unit: mm)**



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<http://moschip.ru/get-element>

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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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